Unraveling quantum pathways interference in two-color coherent control of photoemission with bias voltages

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I. INTRODUCTION

Coherent control steers a quantum system from an initial state to a target state by controlling quantum interference phenomena via an external field, which is central to vast applications ranging from quantum information processing to attosecond physics. Here, we analyze the quantum pathways interference in two-color coherent control of photoemission using exact analytical solutions of the time-dependent Schrödinger equation. The theory includes all possible quantum pathways and their interference terms. Constructive (or destructive) interferences among the pathways leads to the maximum (or minimum) emission with varying phase delay of the two-color lasers. It is found that increasing the intensity ratio of the second harmonic ($2\omega$) to fundamental ($\omega$) lasers results in less contribution from the $\omega$ pathway (absorption of $\omega$ photons only) and more contribution from multicolor pathway (simultaneous absorption of both $\omega$ and $2\omega$ photons) and $2\omega$ pathway (absorption of $2\omega$ photons only), and therefore stronger pathways interference and increased visibility larger than 95%. Increasing bias voltages shifts the dominant emission to processes with lower-order photon absorption, which sequentially decreases the interference between the $\omega$ and the $2\omega$ pathways, and between single-color and multicolor pathways, leading to two peaks in the visibility.

II. RESULTS

The one-dimensional (1D) model is illustrated in Fig. 1(a). Electrons with initial energy of $\varepsilon$ emit through the metal-vacuum interface ($x = 0$) due to DC field $F_0$ and two-
FIG. 1. (a) Energy diagram for photoemission from a metal surface induced by two-color laser fields \( f(t) = F_1 \cos(\omega t) + F_2 \cos(2\omega t + \theta) \) under a DC field \( F_0 \). Red and blue arrows depict quantum pathway model, with pathway I: absorption of \((4 + k)\) fundamental photons (red arrow); pathway II: absorption of \((2 + k)\) fundamental photons and 1 second-harmonic photon (blue arrow); pathway III: absorption of 2 second-harmonic photons and \( k \) fundamental photons. (b) Electron transmission probability from initial energy \( \varepsilon = \mathcal{E}_F \), \( D(\varepsilon = \mathcal{E}_F) \), as a function of 2\( \omega \) laser field \( F_2 \) and phase delay \( \theta \), with \( F_1 = 2.6 \text{ V/nm} \) and \( F_0 = 0 \). (c) Coefficients of Fourier series expansion for \( D(\tau) \) for \( F_2 = 0.05, 0.3, \) and 0.55 V/nm. (d) Fourier series coefficients at angular frequency of 0 \((n = 0)\), 2\( \omega \) \((n = 1)\), and 4\( \omega \) \((n = 2)\) as a function of \( F_2^2 \). Scatters represent coefficients from Fourier series expansion of \( D(\tau) \) from the exact quantum model in Eqs. (2) and (3), and solid curves are fitted from the quantum pathway model in Eq. (4). (e) Decomposed electron transmission probability, with blue curves the zero-frequency terms and red curves the oscillatory terms (2\( \omega \) and 4\( \omega \) terms). (f) Electron transmission \( D(\varepsilon) \) through each quantum pathway (top) and their interference terms (bottom).

color laser field \( f(t) = F_1 \cos(\omega t) + F_2 \cos(2\omega t + \theta) \), where \( F_1 \) and \( F_2 \) are the magnitudes of the fundamental and second-harmonic electric fields, respectively, \( \omega \) is the angular frequency of the fundamental laser, \( \theta = 2\omega \tau \) is the relative phase between the fundamental and second-harmonic, with \( \tau \) the corresponding time delay. For simplicity, the fields are assumed to be perpendicular to the metal surface and abruptly cut off inside the metal [5,6,22,34]. The potential barrier seen by electrons inside the metal reads

\[
\phi(x, t) = \begin{cases} 
0, & x < 0 \\
V_0 - \varepsilon f(t)x - eF_0x, & x \geq 0
\end{cases}
\]

where \( V_0 = \mathcal{E}_F + W_{\text{eff}} \), \( \mathcal{E}_F \) is the Fermi energy of the metal, and \( W_{\text{eff}} = W_0 - W_{\text{Schottky}} \) is the effective work function with \( W_0 \) the nominal work function and \( W_{\text{Schottky}} = 2\sqrt{\varepsilon^2 F_0^2/16\pi\varepsilon_0} \) the Schottky barrier lowering due to DC field \( F_0 \), \( \varepsilon (\gtrsim 0) \) is the elementary charge, and \( \varepsilon_0 \) is the vacuum permittivity. By exactly solving TDSE subject to the potential barrier in Eq. (1), the time-averaged electron transmission probability from energy level \( \varepsilon \) is obtained as [5,6]

\[
D(\varepsilon) = \sum_{l=-\infty}^{\infty} w_l(\varepsilon),
\]

where \( w_l(\varepsilon) \) represents the electron emission through \( l \)-photon processes, with \( l < 0 \) being multiphoton emission, \( l = 0 \) direct tunneling, and \( l > 0 \) multiphoton absorption processes [5,6,33–36]. The expression of \( w_l \) is summarized in the Appendix. More detailed derivation can be found in Ref. [5] for \( F_0 = 0 \) and in Ref. [6] for \( F_0 \neq 0 \). It is important to note that although \( l \) in Eq. (2), as written, is referred to the number of fundamental photons \( h\omega \), it also includes the possible processes of substituting two fundamental photons \( 2h\omega \) with a single second-harmonic photon \( h(2\omega) \), illustrated in the three possible pathways in Fig. 1(a), as well as arbitrary multiples of such substitutions.

Figure 1(b) shows the electron emission probability from Fermi level \( D(\varepsilon = \mathcal{E}_F) \) as a function of second-harmonic laser field \( F_2 \) and relative phase \( \theta \), with fundamental laser field \( F_1 = 2.6 \text{ V/nm} \) and DC field \( F_0 = 0 \). The metal is assumed as gold, with \( W_0 = 5.1 \text{ eV} \) and \( \mathcal{E}_F = 5.53 \text{ eV} \). The fundamental laser has the wavelength of 800 nm (photon energy of 1.55 eV). For
where \( \alpha \), \( \zeta \), and \( \beta \) are the weights for pathways I, II, and III, respectively, and \( K_i \) is the prefactor for each term as a power function of \( F_2^2 \). Equating the total transmission probability \( D(\tau) \) in Eq. (3) with the sum of all the probabilities in Eqs. (4a)–(4f) enables us to extract straightforwardly the weights \( \alpha \), \( \zeta \), and \( \beta \) from the Fourier coefficients.

By setting \( k = 0 \) (see Fig. S2 for fitting \( K_i \)), \( F_2^2 \) as a function of \( F_2^2 \) in Supplemental Material [37]), the fitted \( K_i \), \( D_i \), and \( D_{I\&II} \) in Fig. 1(d) yield \( \alpha = 1.18 \times 10^{-3} \text{nm}^2/\text{V}^2 \), \( \zeta = 2.93 \times 10^{-5} \text{nm}^3/\text{V}^3 \), and \( \beta = 3.17 \times 10^{-4} \text{nm}^2/\text{V}^2 \). With these \( K_i \) weights [Fig. 1(d)], the transmission probability \( D(\varepsilon = E_F) \) is decomposed into a DC term (zero-frequency term) and an oscillatory term (consisting of 2\( \omega \) and 4\( \omega \) terms), as exemplified in Fig. 1(e) for \( F_2 = 0.3 \text{ V/\text{nm}} \). Fourier series expansion with these fitting parameters perfectly reproduces the raw data from our quantum model obtained from Eq. (2).

Photoemission through each of the channels in Eq. (4) is explicitly shown in Fig. 1(f). It is clear that pathways I and II in combination form the majority of the constant baseline emission channels, around which the transmission probability oscillates with the relative phase \( \theta \). The strongest interference is between pathways I and II. Interference terms, and therefore the total transmission probability, can be strongly tuned by the phase difference \( \theta \), with maximum at \( \theta \approx \pi/2 \) and minimum at \( \theta \approx 1.8\pi \), as shown in Figs. 1(e) and 1(f).
FIG. 2. (a) Electron transmission probability $D_i$ through each channel and (b) the corresponding normalized transmission probability $D_i/D$ at maximum of $D(\varepsilon = E_F)$ in $\theta$ domain for a given $F_2$. (c) $D_i$ and (d) $D_i/D$ at minimum of $D(\varepsilon = E_F)$ in $\theta$ domain for a given $F_2$. Here, $F_1 = 2.6\, \text{V/nm}$ and $F_0 = 0$.

Material [37], which reconfirms the above observation. When $F_2$ increases to $0.55\, \text{V/nm}$, emission through pathway II and interference II&III become the dominant DC and oscillatory terms, respectively.

Figure 3 shows the effect of fundamental laser field on the modulation of quantum interference and the contribution of each pathway. As shown in Fig. 3(a), when $F_1$ increases, the visibility increases and then decreases, with the maximum at $F_1 = 2.6\, \text{V/nm}$, corresponding to the intensity ratio of second harmonic to the fundamental of 1.3%, with fixed second-harmonic field $F_2 = 0.3\, \text{V/nm}$ and DC field $F_0 = 0$. The transmission probability from initial energy level $\varepsilon = E_F$ as a function of relative phase $\theta$ is shown as inset in Fig. 3(a) under various fundamental laser fields $F_1$. As $F_1$ increases, $D(\varepsilon = E_F)$ is greatly enhanced. The oscillation magnitude gradually decreases for $F_1 > 2.6\, \text{V/nm}$, consistent with the decreasing visibility in Fig. 3(a).

The decrease of the visibility is ascribed to smaller two-color laser intensity ratio, which results in relatively less contribution from pathways II and III and therefore the interference terms, as shown in Fig. 3(b). When $F_1 < 2\, \text{V/nm}$ (or $F_2/F_1 > 0.15$), the dominant emission is through pathway III and the interference term II&III. As $F_1$ increases, electron emission through pathway I and interference I&II increases greatly. As $F_1$ reaches $\sim 3.7\, \text{V/nm}$, the contribution from pathway I exceeds that of the interference term I&II. For $F_1 > 3.7\, \text{V/nm}$, while I&II remains the dominant interference term, its contribution to photoemission continues to decrease.

As another key knob to the coherent control of electron emission by two-color lasers, the effect of DC field is shown in Fig. 4. In Fig. 4(a), $D(\varepsilon = E_F)$ is plotted as a function of relative phase $\theta$ under various DC fields $F_0$. As $F_0$ increases, transmission probability is greatly enhanced due to the lowering and narrowing of the surface potential barrier, which opens emission channels of lower order (cf. Fig. 2 in Ref. [6]). The minimum shifts from $\theta \sim 1.7\pi$ to $\theta \equiv \pi$, which indicates the suppression of high-order $4\omega$ terms. Figure 4(b) shows the visibility as a function of $F_0$ under different second-harmonic laser fields with $F_1 = 2.6\, \text{V/nm}$. For $F_2 \leq 0.3\, \text{V/nm}$, the maximum visibility is observed at $F_0 \equiv 0.5\, \text{V/nm}$, whereas for $F_2 \geq 0.4\, \text{V/nm}$, the maximum occurs at $F_0 = 0$. Another peak also appears at $F_0 \equiv 1.75\, \text{V/nm}$ for all cases. When $F_0 > 1.75\, \text{V/nm}$, visibility decreases. As $F_0$ reaches 3 V/nm, visibility drops to almost 0 for all cases.

The nonlinear dependence of visibility on DC fields can be explained by looking at the Fourier series coefficient, as shown in logarithm scale in Fig. 4(c). When $F_0 \geq 0.5\, \text{V/nm}$, the high-frequency component at $4\omega$ is suppressed compared to the 0 and $2\omega$ terms. As $F_0$ further increases, the difference between the coefficient at zero frequency and that at
FIG. 3. (a) Visibility as a function of $F_1$. Gray solid curve: calculated directly from the data by the quantum model in Eq. (2); black scatters: calculated from visibility $= \frac{D_{I\&II}}{D_I + D_{II}}$ with $D_I$, $D_{II}$, and $D_{I\&II}$ from Eq. (4) using fitted parameters; inset: transmission probability as a function of relative phase under different $F_1$. (b) Normalized transmission probability over the total transmission probability at maximum of $D(\varepsilon = E_F)$ in $\theta$ domain as a function of $F_1$. Here, we fix $F_2 = 0.3$ V/nm and $F_0 = 0$.

FIG. 4. (a) $D(\varepsilon = E_F)$ as a function of phase delay $\theta$ under various DC fields $F_0$. (b) Visibility as a function of $F_0$ under various $F_2$. (c) Fourier series coefficients under various $F_0$. (d) Normalized transmission probability over the total transmission probability at maximum of $D(\varepsilon = E_F)$ in $\theta$ domain as a function of $F_0$. Here, we use $F_1 = 2.6$ V/nm and $F_2 = 0.3$ V/nm in (a), (c), and (d).
2\omega increases. When \( F_0 \) is sufficiently large, the component at 2\omega becomes also negligibly small compared to the zero-frequency component. Thus, the peaks around 0–0.5 V/nm and 1.75 V/nm in Fig. 4(b) can be attributed to the 4\omega and 2\omega components, respectively. Note the peaks are also observed in previous experiments (inset in Fig. 5 of Ref. [32]). Normalized transmission probability at maximum of \( D(\varepsilon = E_F) \) in the \( \theta \) domain in Fig. 4(d) also confirms this observation. Since the 4\omega term is negligible for the majority of the cases, only pathways I, II, and their interference I&II are considered here for simplicity. When \( F_0 \) < 0.5 V/nm, those two pathways and the interference between them cannot account for the total emission, as the sum of those terms is smaller than 1, indicating additional contributions from the 4\omega term are needed in this regime. As \( F_0 \geq 0.5 \) V/nm, the sum approaches 1. The contribution from pathway I to the total emission increases, while the contribution from the other two channels decreases. It is important to note that, different from the physical meaning of absorption of 4 photons of fundamental laser in the absence of DC field, pathway I with positive \( F_0 \) also includes contributions from direct tunneling, photon-assisted tunneling, and photon-emission tunneling (cf. Fig. 2 in Ref. [6]), which are all captured by the prefactors with power of \( k \) in Eq. (4).

III. CONCLUSION

In conclusion, we analyze quantum pathways interference in two-color coherent control of photoemission using exact analytical solutions of the TDSE including DC bias. The exact theory includes the contribution from all possible quantum pathways and their interference terms. Interference among pathways physically explains the observed modulation of photoemission current by the relative phase between two-color lasers. Effects of two-color laser fields and DC bias field on the weights of each pathway and interference between them are explicitly demonstrated. It is found that increasing the intensity ratio of the second harmonic to fundamental lasers would result in more contribution from multicolor pathway and the single-color pathway of absorption of 2\omega photons, and therefore stronger interference between them and increased visibility more than 95%. Increasing bias voltages opens out lower photon order channels including photoassisted tunneling and direct tunneling, which inhibits contribution from both single-color and multicolor multiphoton absorption. Implied by the quantum pathways interference model is that the lower-order photon-assisted and direct tunneling processes are also incorporated in the different pathways with the presence of the DC bias. As a result, interferences through different pathways are sequentially decreased with the increase of DC bias voltage, leading to the subsequent suppression of 4\omega and then 2\omega components in the Fourier analysis of current modulation with respect to the relative phase between the two-color lasers. This helps explain the two peaks in the visibility as a function of bias voltage.

Our study provides direct theoretical foundation to confirm the coherent emission physics of replacing two fundamental photons with one second-harmonic photon despite various possible pathways. Our quantum theory and the corresponding pathways model are applicable to arbitrary driving-laser frequency, intensity (below the material damage threshold), and material properties. Our study provides insights into two-color laser-induced photoelectron emission dynamics and more general coherent control schemes of quantum systems ranging from single atoms and molecules [38,39], nano-objects [8,40], and material surfaces and interfaces [26,41–44]. Manipulating ionization pathways and the corresponding quantum phases between pathways enable us to develop methods for controlling excitation and ionization processes in atoms, molecules, and materials under strong laser fields [45–49]. Therefore, identifying and quantifying quantum pathways and corresponding quantum phases are fundamentally important to both the understanding of the photoionization dynamics and the characterization of the atomic and molecular structures. Our analysis using the exact analytical quantum model in combination with the Fourier analysis can provide a systematic investigation into the parametric dependence of each pathway as well as interference terms among them. The parametric scaling of different pathways would be helpful in the optimization of the input laser parameters to achieve coherent control through a specific pathway in a given quantum system.

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APPENDIX

For completeness, we provide the expression for the key results of our quantum model developed in Refs. [5,6]. More details about the derivation of these results can be found in Refs. [5] and [6]. With the assumptions listed in the main text, the electron wave function \( \psi(x,t) \) is solved exactly from the 1D time-dependent Schrödinger equation:

\[
\frac{i\hbar}{\partial x} \frac{\partial \psi(x,t)}{\partial t} = -\frac{\hbar^2}{2m} \frac{\partial^2 \psi(x,t)}{\partial x^2} + \phi(x,t) \psi(x,t),
\]

where \( \hbar \) is the reduced Planck constant, \( m \) is the electron mass, \( x \) is the distance to the metal surface, and \( \phi(x,t) \) is the potential barrier given in Eq. (1) in the main text.

The exact analytical solution for electron waves inside the metal (\( x < 0 \)) is

\[
\psi_I(x,t) = \exp \left( -i\frac{\varepsilon}{\hbar} t + ik_0 x \right) + \sum_{l=-\infty}^{\infty} R_l \times \exp \left( -i \frac{\varepsilon + i\hbar \omega}{\hbar} t - ik_l x \right), \quad x < 0,
\]

where \( \varepsilon \) is the electron initial energy, \( k_0 = \sqrt{2me/\hbar^2} \) and \( k_l = \sqrt{2m(\varepsilon + i\hbar \omega)/\hbar^2} \) are the electron wave numbers, and \( R_l \) is the reflection coefficient of the incident electron wave after \( l \)-photon process.
The exact analytical solution for the transmitted electron wave outside the metal \((x \geq 0)\) is obtained using Truscott transformations \([5,6,50]\) from Eq. (A1) and separation of variables, which reads
\[
\psi_{TL}(x, t) = \sum_{l=\infty}^{\infty} T_l \exp \left[ i \sqrt{\frac{2mE_i}{\hbar^2}} \left( x + \frac{eF_1 \cos \omega t}{m_0^2} + \frac{eF_2 \cos(2\omega t + \theta)}{4m_0^2} \right) \right] \times \exp \left[ -i \frac{\varepsilon + \hbar \omega}{\hbar} t + i \frac{x}{\hbar} L + i \frac{\varepsilon^2}{8\hbar m_0^3} M - i \frac{e^2 F_1 F_2}{8\hbar m_0^3} N \right], \quad x \geq 0, \tag{A3a}
\]
when \(F_0 = 0\), and
\[
\psi_{TL}(x, t) = \sum_{l=\infty}^{\infty} T_l \exp \left[ -i \frac{\varepsilon + \hbar \omega}{\hbar} t + i \frac{x}{\hbar} L + i \frac{\varepsilon^2}{8\hbar m_0^3} M - i \frac{e^2 F_1 F_2}{8\hbar m_0^3} N \right], \quad x \geq 0, \tag{A3b}
\]
when \(F_0 \neq 0\), where \(E_l = \varepsilon + \hbar \omega - \frac{V_0 - U_{p1} - U_{p2}}{}\) and ponderomotive energy \(U_{p1} = \frac{eF_1^2}{4m_0}\) and \(U_{p2} = \frac{e^2 F_1^2}{8m_0}\) due to fundamental and second-harmonic fields, respectively, \(L = \frac{eF_1 \sin \omega t}{\omega} + \frac{e^2 F_1 \sin(2\omega t + \theta)}{2\omega^2} + \) \(M = F_1^2 \sin 2\omega t + F_1 \sin(2\omega t + \theta), \quad N = \frac{\sin(3\omega t + \theta)}{3\omega}, \quad \eta_l = \frac{2\eta_1}{3} \left( \frac{2meF_1}{\hbar^2} \right)^\frac{1}{3} (x + \frac{F_0}{\hbar}) \right) \right. \]
\]
\]
\]
\]
\]

Applying boundary conditions that \(\psi(x, t)\) and \(\partial \psi(x, t)/\partial x\) are continuous at the metal-vacuum interface \(x = 0\), we obtain the following relationship:
\[
2k_0 \delta(s) = \sum_{l=\infty}^{\infty} T_l [k, P_l(s) + Q_l(s)]. \tag{A4}
\]

Here, \(\delta\) is Dirac delta function, \(P_l(s) = (1/2\pi) \int_0^{2\pi} \tilde{P}_l(\omega) e^{-i(s-\omega)\tilde{d}(\omega)} d(\omega)\) and \(Q_l(s) = (1/2\pi) \int_0^{2\pi} \tilde{Q}_l(\omega) e^{-i(s-\omega)\tilde{d}(\omega)} d(\omega)\) are the \((l-s)\)th Fourier transform coefficients of \(p_l(\omega)\) and \(q_l(\omega)\) respectively:
\[
\tilde{p}_l(\omega) = \exp \left[ i \sqrt{\frac{2mE_i}{\hbar^2}} \left( \frac{eF_1 \cos \omega t}{m_0^2} + \frac{eF_2 \cos(2\omega t + \theta)}{4m_0^2} \right) \right] \times \exp \left[ i \frac{\varepsilon^2}{8\hbar m_0^3} M - i \frac{e^2 F_1 F_2}{4\hbar m_0^3} N \right], \tag{A5a}
\]
\[
\tilde{q}_l(\omega) = \left[ \sqrt{\frac{2mE_i}{\hbar^2}} + \frac{L}{\hbar} \right] \tilde{p}_l(\omega), \tag{A5b}
\]
when \(F_0 = 0\), and
\[
p_l(\omega) = [P_l(-\eta_1) - iB_l(-\eta_1)] \exp \left[ -i \frac{\varepsilon^2 F_1 F_2 \sin \omega t}{8\hbar m_0^3} \right], \tag{A5c}
\]
when \(F_0 \neq 0\), where \(\eta_l(x) = \eta_1(x) = 0\).

With the electron transmission coefficient \(T_l\) solved from Eq. (A4), the time-averaged probability of electron transmission from initial energy of \(\varepsilon\) through the \(l\)-phonon process is given as
\[
w_l(\varepsilon) = \left[ \frac{\hbar}{8k_0} \left[ \begin{array}{c|c} \frac{1}{2\pi} \text{Im} \left[i \sqrt{\frac{2mE_i}{\hbar^2}} |T_l|^2 \right] & F_0 = 0 \\
\frac{1}{2\pi} \left( \frac{2meF_1}{\hbar^2} \right)^\frac{1}{3} |T_l|^2 & F_0 \neq 0
\end{array} \right] \right]
\]
and the total electron transmission probability for an initial energy of \(\varepsilon\) is a sum of \(w_l\) through all the \(l\)-phonon processes, which is Eq. (2) in the main text.

Unraveling quantum pathways interference in two-color coherent control of photoemission with bias voltages

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1. Transmission probability and visibility

Figure S1(a) shows the electron emission probability from initial energy of Fermi level as a function of second harmonic laser field $F_2$ and relative phase $\theta$, with fundamental laser field $F_1 = 2.6$ V/nm and dc field $F_0 = 0$. Maxima of $D(\varepsilon = E_F)$ in a period of $2\pi$ for a given $F_2$ are observed at $\theta \approx \pi/2$, which are indicated by red pentagrams. Minima of $D(\varepsilon = E_F)$ in a period of $2\pi$ for a given $F_2$ are observed at $\theta \approx 3\pi/2$ when $F_2 \leq 0.4$ V/nm and at $\theta \approx \pi$ when $F_2 > 0.4$ V/nm, denoted as yellow pentagrams. Visibility, defined as the ratio of the difference between the maximum and the minimum of transmission probability in $\theta$ domain to the summation of them [1]–[3], quantifies the modulation degree due to relative phase $\theta$, which is shown as a function of $F_2$ in Fig. S1(b). Visibility increases when $F_2$ increases for $F_2 \leq 0.3$ V/nm and keeps almost constant for $F_2 > 0.3$ V/nm. Scatters denote visibility calculated by $D_{III}/(D_I + D_{III})$ using Eq. (4) in main text with fitted parameters. It agrees well with visibility directly calculated from $D(\varepsilon = E_F)$ in Eq. (2) for $F_2 < 0.2$ V/nm in Fig. 1S(a). This is due to the weak emission through pathway III and their related interference for small $F_2$. Therefore, two-pathway model can give a good explanation for the case of low intensity mixture ratio of two-color lasers, which is consistent with experimental observations [1].
Figure S1. (a) Electron transmission probability from initial energy $\epsilon = E_F$, as a function of second harmonic laser field $F_2$ and phase delay $\theta$, with $F_1 = 2.6\text{ V/nm}$ and $F_0 = 0$. Red and yellow pentagrams depict maxima and minima in $\theta$ domain for a given $F_2$, respectively. (b) Visibility, defined as the ratio of the difference between the maximum and minimum of $D(\epsilon = E_F)$ in $\theta$ domain and the sum of them, as a function of $F_2$. Solid gray curve is calculated from our quantum model in Eq. (2), and black scatters are for visibility $= D_{I\&II}/(D_I + D_{II})$, by fitting results with $D_I$s obtained from Eq. (4).

2. Prefactor fitting

The prefactors $K_i$ in Eq. (4), are shown as a function of $F_1^2$ as scatters in Fig. S2. They are fitted by power functions of $F_1^2$, with fitting results shown as solid curves. The fitting power orders for prefactors of $K_I$, $K_{II}$, $K_{I\&II}$, $K_{II\&III}$, and $K_{I\&III}$ are 3.84, 2.43, 3.14, 0.9, and 1.53, respectively. These values are close to the corresponding power orders of 4, 2, 3, 1, and 2 with $k = 0$ in Eq. (4), which validates the quantum pathway model and also indicates the dominant absorption of equivalent 4 fundamental photons for $\epsilon = E_F$. It should be noted that $K_{III}$ is not fitted here, since it is independent of $F_1^2$ for $k = 0$. Figure S2(a) shows that $D_{III}$ decreases slightly as $F_1^2$ increases.

With $k = 0$, $\alpha$, $\zeta$, and $\beta$ can be calculated from $K_I$, $K_{II}$, and $K_{III}$ respectively for a given $F_1$. Those values are used to calculate $K_{I\&II}$, $K_{II\&III}$, and $K_{I\&III}$, which are shown as dashed curves in Fig. S2(c). Good agreement is achieved between the dashed curves and the scatters obtained from Eq. (4), which further confirms the validity of the quantum pathway model.
3. Decomposed transmission probability

Using parameters obtained from fitting the Fourier series coefficients with the quantum interference model, electron transmission probability in Eqs. (2) and (3) is decomposed into components corresponding to three pathways and interference terms among them, as in Eq. (4). Three cases, i.e., $F_2 = 0.05$, 0.3, and 0.55 V/nm with $F_1 = 2.6$ V/nm and $F_0 = 0$, are exemplified in Fig. S3. It is obvious that transmission probability through pathways II and III as well as the interference terms I&III and II&III increases as $F_2$ increases.
Figure S3. Decomposed electron transmission probability by Fourier series expansion. (a), (b), and (c) 0 frequency terms for $F_2 = 0.05$, 0.3 and 0.55 V/nm, respectively. (d), (e), and (f) oscillatory terms ($2\omega$ and $4\omega$ terms) for $F_2 = 0.05$, 0.3 and 0.55 V/nm, respectively.

